## NSN 5961-01-507-8461

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-507-8461 **Inclosure Material:** Plastic **Overall Length:** 0.335 inches **Terminal Length:** 1.000 inches **Overall Diameter:** 0.180 inches **End Application:** 4920-01-495-9100 **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 143.0 breakdown voltage, dc and 158.0 breakdown voltage, dc **Current Rating Per Characteristic:** 2.90 amperes source cutoff current universal **Power Rating Per Characteristic:** 600.0 milliwatts small-signal input power, common-emitter peak **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Product Name:** Transient absorption zener **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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